

#### MMBT3904M NPN General Purpose Transistor

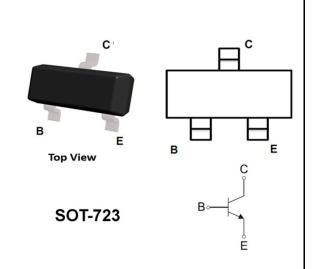
#### **General description**

• NPN General Purpose Transistor

#### **FEATURES**

- SOT-723 General Purpose Transistors.
- VCEO 40V
- Ic 200mA
- PC 100mW
- Complementary to MMBT3906M
- Small Outline Surface Mount Package.
- RoHS Compliant / Green EMC.

| Туре    | MMBT3904M |  |  |
|---------|-----------|--|--|
| Marking | 1N        |  |  |



#### Absolute Maximum Ratings(Ta=25°C)

| Parameter                                   | Symbol            | Limit            | Unit       |
|---|-------------------|------------------|------------|
| Collector-Base Voltage                      | Vсво              | 60               | V          |
| Collector-Emitter Voltage                   | V <sub>CEO</sub>  | 40               | V          |
| Emitter-Base Voltage                        | VEBO              | 6                | V          |
| Collector Current -Continuous               | Ic                | 0.2              | А          |
| Power Dissipation                           | Pc                | 0.1              | W          |
| Thermal Resistance from Junction to Ambient | R <sub>θ</sub> JA | 1250             | °C/W       |
| Junction Temperature                        | Tı                | 150              | $^{\circ}$ |
| Storage Temperature                         | Тѕтб              | <b>-</b> 55∼+150 | $^{\circ}$ |



## ELECTRICAL CHARACTERISTICS @ 25°C Unless Otherwise Specified

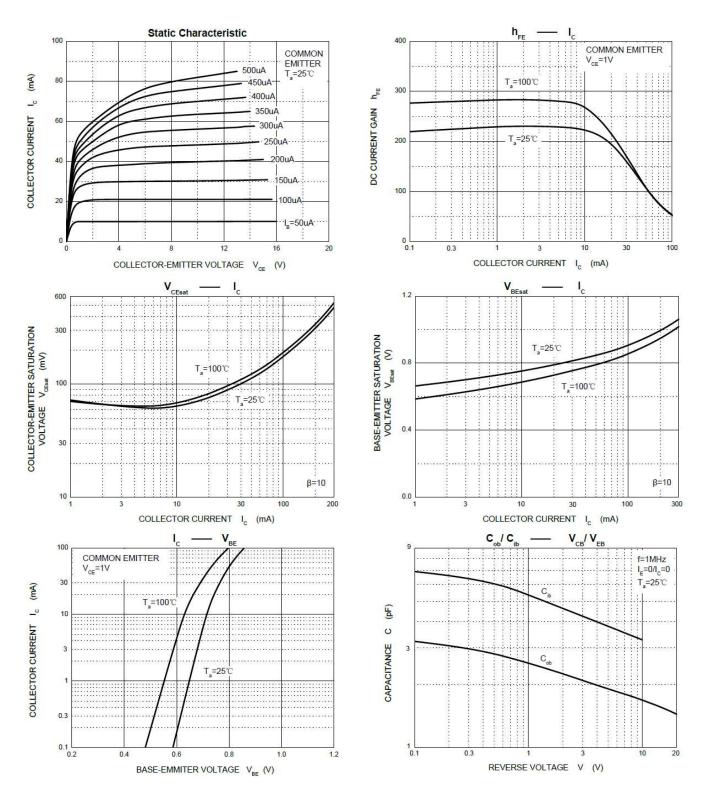
| Parameter                            | Symbol   | Conditions   | Min  | Тур | Max  | Units |
|--------------------------------------|----------|--|------|-----|------|-------|
| Collector-base breakdown voltage     | V(BR)CBO | Ic=10μA,Iε=0                                       | 60   |     |      | V     |
| Collector-emitter breakdown voltage  | V(BR)CEO | Ic=1mA,I <sub>B</sub> =0                           | 40   |     |      | V     |
| Emitter-base breakdown voltage       | V(BR)EBO | I <sub>E</sub> =10μA,I <sub>C</sub> =0             | 6    |     |      | V     |
| Collector cut-off current            | Icex     | Vce=30V,Veb(off)=3V                                |      |     | 50   | nA    |
| Emitter cut-off current              | ІЕВО     | V <sub>EB</sub> =5V,I <sub>C</sub> =0              |      |     | 100  | nA    |
|                                      | hfe      | Vce=1V,Ic=0 mA                                     | 40   |     |      |       |
| DC current gain                      |          | Vce=1V,Ic=1mA                                      | 70   |     |      |       |
|                                      |          | Vce=1V,Ic=10mA                                     | 100  |     | 300  |       |
|                                      |          | VcE=1V,Ic=50mA                                     | 60   |     |      |       |
| Collector-emitter saturation voltage |          | Ic=10mA,Iв=1mA                                     |      |     | 0.2  | V     |
|                                      | VCE(sat) | Ic=50mA,Iв=5mA                                     |      |     | 0.3  | V     |
| Base-emitter saturation voltage      | VBE(sat) | I <sub>C</sub> =10mA,I <sub>B</sub> =1mA           | 0.65 |     | 0.85 | V     |
|                                      |          | Ic=50mA,Iв=5mA                                     |      |     | 0.95 | ٧     |
| Transition frequency                 | fτ       | V <sub>CE</sub> =20V,I <sub>C</sub> =10mA,f=100MHz | 300  |     |      | MHz   |
| Output capacitance                   | Сов      | Vcb=5V,IE=0,f=1MHz                                 |      |     | 4    | pF    |
| Input capacitance                    | Сіь      | Veb=0.5V,Ic=0,f=1MHz                               |      |     | 8    | pF    |
| Noise figure                         | NF       | Vc=5V,Ic=0.1mA,f=1MHz,R <sub>S</sub> =1kΩ          |      |     | 5    | dB    |



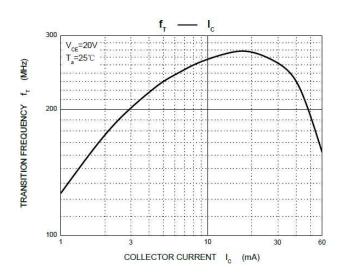
| Parameter    | Symbol         | Conditions   | Min | Тур | Max | Units |
|--------------|----------------|--|-----|-----|-----|-------|
| Delay time   | <b>t</b> d     |  |     |     | 35  | ns    |
| Rise time    | tr             | Vcc=3V,VBE(off)=-0.5V,<br>Ic=10mA,I <sub>B1</sub> =1mA |     |     | 25  | ns    |
| Storage time | ts             |  |     |     | 200 | ns    |
| Fall time    | t <sub>f</sub> | Vcc=3V,lc=10mA lв1=lв2=1mA                             |     |     | 50  | ns    |

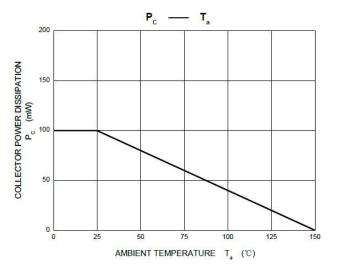


#### TYPICAL CHARACTERICTIC

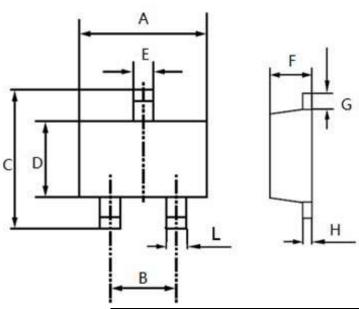








#### **PACKAGE DIMENSIONS**



| Symbol  | Dimensions In Millimeters |       |  |
|---------|---------------------------|-------|--|
| Зуппоот | Min                       | Max   |  |
| А       | 1.100                     | 1.300 |  |
| В       | 0.8typ                    |       |  |
| С       | 1.100                     | 1.300 |  |
| D       | 0.700                     | 0.900 |  |
| E       | 0.200                     | 0.300 |  |
| F       | 0.400                     | 0.500 |  |
| G       | 0.150                     | 0.250 |  |
| Н       | 0.060                     | 0.160 |  |
| L       | 0.150                     | 0.250 |  |



### **Important Notice and Disclaimer**

DOESHARE has used reasonable care in preparing the information included in this document, but DOESHARE does not warrant that such information is error free. DOESHARE assumes no liability whatsoever for any damages incurred by you resulting from errors in or omissions from the information included herein.

DOESHARE no warranty, representation or guarantee regarding the documents, circuits and products specification, DOESHARE reservation rights to make changes for any documents, products, circuits and specifications at any time without notice.

Purchasers are solely responsible for the choice, selection and use of the DOESHARE products and services described herein, and DOESHARE assumes no liability whatsoever relating to the choice, selection or use of the products and services described herein.

No license, express or implied, by implication or otherwise under any intellectual property rights of DOESHARE.

Resale of DOESHARE products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by DOESHARE for the DOESHARE product or service described herein and shall not create or extend in any manner whatsoever, any liability of DOESHARE.

### **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Bipolar Transistors - BJT category:

Click to view products by Doeshare manufacturer:

Other Similar products are found below:

619691C MCH4017-TL-H MMBT-2369-TR BC546/116 BC557/116 BSW67A NJVMJD148T4G NTE123AP-10 NTE153MCP NTE16

NTE195A NTE92 C4460 2N4401-A 2N6728 2SA1419T-TD-H 2SA2126-E 2SB1204S-TL-E 2SC2712S-GR,LF 2SC5488A-TL-H

2SD2150T100R SP000011176 2N2907A 2N3904-NS 2N5769 2SC2412KT146S 2SD1816S-TL-E CPH6501-TL-E MCH4021-TL-E

MJE340 US6T6TR NJL0281DG 732314D CPH3121-TL-E CPH6021-TL-H 873787E IMZ2AT108 UMX21NTR MCH6102-TL-E FP204
TL-E NJL0302DG 2N3583 2SA2014-TD-E 2SC2812-5-TB-E 30A02MH-TL-E NSV40301MZ4T1G NTE13 NTE26 NTE282 NTE323